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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/783,495	02/20/2004	Yung-Cheng Chen	N1085-00251	2148
54657	7590	08/23/2006	[TSMC2003-083]	
DUANE MORRIS LLP IP DEPARTMENT (TSMC) 30 SOUTH 17TH STREET PHILADELPHIA, PA 19103-4196			EXAMINER NORTON, JENNIFER L	
			ART UNIT	PAPER NUMBER
			2121	

DATE MAILED: 08/23/2006

Please find below and/or attached an Office communication concerning this application or proceeding.

Office Action Summary

Application No.

10/783,495

Applicant(s)

CHEN ET AL.

Examiner

Jennifer L. Norton

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-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --

Period for Reply

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) OR THIRTY (30) DAYS, WHICHEVER IS LONGER, FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

Status

- 1) ☒ Responsive to communication(s) filed on 30 May 2006.
- 2a) ☒ This action is **FINAL**. 2b) ☐ This action is non-final.
- 3) ☐ Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

Disposition of Claims

- 4) ☒ Claim(s) 1-22 is/are pending in the application.
- 4a) Of the above claim(s) _____ is/are withdrawn from consideration.
- 5) ☐ Claim(s) _____ is/are allowed.
- 6) ☒ Claim(s) 1-22 is/are rejected.
- 7) ☐ Claim(s) _____ is/are objected to.
- 8) ☐ Claim(s) _____ are subject to restriction and/or election requirement.

Application Papers

- 9) ☐ The specification is objected to by the Examiner.
- 10) ☒ The drawing(s) filed on 6 August 2004 is/are: a) ☒ accepted or b) ☐ objected to by the Examiner.
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).
- 11) ☐ The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.

Priority under 35 U.S.C. § 119

- 12) ☐ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
- a) ☐ All b) ☐ Some * c) ☐ None of:
1. ☐ Certified copies of the priority documents have been received.
 2. ☐ Certified copies of the priority documents have been received in Application No. _____.
 3. ☐ Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).

* See the attached detailed Office action for a list of the certified copies not received.

Attachment(s)

- | | |
|--|---|
| 1) <input type="checkbox"/> Notice of References Cited (PTO-892) | 4) <input type="checkbox"/> Interview Summary (PTO-413)
Paper No(s)/Mail Date. _____ |
| 2) <input type="checkbox"/> Notice of Draftsperson's Patent Drawing Review (PTO-948) | 5) <input type="checkbox"/> Notice of Informal Patent Application (PTO-152) |
| 3) <input type="checkbox"/> Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08)
Paper No(s)/Mail Date _____ | 6) <input type="checkbox"/> Other: _____ |

DETAILED ACTION

1. The following is a **Final Office Action** in response to the Amendment received on 30 May 2006. Claims 5, 7-8, 12, 14-18 and 21-22. Claims 1-22 are pending in this application.

Claim Objections

2. The amendment to the claims was received on 30 May 2006. The corrections to the claims are acceptable.

3. Claim 12 is objected to because of the following informalities:

Claim 12, line 5 includes the spelling error of "feed back". "Feedback" should be spelled the same way in all claims to maintain continuity.

Appropriate correction is required.

Claim Rejections - 35 USC § 102

4. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless –

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

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5. Claims 1-4 and 9-11 are rejected under 35 U.S.C. 102(b) as being anticipated by U.S. Patent No. 5,409,538 (hereinafter Nakayama).

6. As per claim 1, Nakayama discloses a method for controlling exposure energy on a wafer substrate, comprising the steps of:

controlling the exposure energy with a feedback process control signal of critical dimension (col. 6, lines 14-20 and 48-55, col. 15, lines 12-21 and Fig. 18), and

further controlling the exposure energy with a feed forward process control signal of a compensation amount that compensates for wafer thickness variations (col. 6, lines 48-55 and col. 15, lines 14-41, i.e. "the results of the correction").

7. As per claim 2, Nakayama discloses combining the feed forward control signal with the feedback process control signal to control the exposure energy (col. 15, lines 14-33 and Fig. 18).

8. As per claim 3, Nakayama discloses supplying the feed forward process control signal by a feed forward controller (col. 15, lines 21-41 and Fig. 18, element 45).

9. As per claim 4, Nakayama discloses controlling the exposure energy by a feed forward control signal of an interlayer thickness measurement (col. 6, lines 48-55, col. 15, lines 8-28 and Fig. 18, element 56).

10. As per claim 9, Nakayama discloses calculating the compensation amount according to a polynomial function with higher order coefficients set at zero (col. 5, lines 17-32 and 38-51).

11. As per claim 10, Nakayama discloses calculating the compensation amount according to a linear function (col. 5, lines 38-51).

12. As per claim 11, Nakayama discloses calculating the compensation amount according to a segmented linear function (col. 5, lines 17-32 and 38-51).

Claim Rejections - 35 USC § 103

13. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negated by the manner in which the invention was made.

14. Claims 5-8 and 12-22 are rejected under 35 U.S.C. 103(a) as being unpatentable over Nakayama in view of U.S. Patent No. 6,798,529 (hereinafter Saka).

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15. As per claim 5, Nakayama teaches controlling the exposure energy by a feed forward control signal of an interlayer thickness measurement (col. 15, lines 8-28 and Fig. 18, element 56).

Nakayama does not expressly teach an interlayer thickness measurement remaining after chemical mechanical planarization.

Saka teaches to an interlayer thickness measurement remaining after chemical mechanical planarization (col. 8, lines 61-63 and col. 13, lines 27-33).

Therefore, it would have been obvious to a person of ordinary skill in the art at the time of applicant's invention to modify the teaching of Nakayama to include an interlayer thickness measurement remaining after chemical mechanical planarization to continuously and in-situ, monitor localized regions of a wafer surface during the chemical mechanical planarization process (col. 5, lines 38-40).

16. As per claim 6, Nakayama teaches calculating the compensation amount according to a polynomial function with a coefficient of the function being based on a measurement of a thickness of a planarized interlayer (col. 6, lines 35-55 and col. 15, lines 17-33).

Nakayama does not expressly teach a measurement of a remaining thickness of a planarized interlayer.

Saka teaches to a measurement of a remaining thickness of a planarized interlayer (col. 8, lines 61-63 and col. 13, lines 27-33).

Therefore, it would have been obvious to a person of ordinary skill in the art at the time of applicant's invention to modify the teaching of Nakayama to include a measurement of a remaining thickness of a planarized interlayer to continuously and in-situ, monitor localized regions of a wafer surface during the chemical mechanical planarization process (col. 5, lines 38-40).

17. As per claim 7, Nakayama teaches to calculating the feedback process control signal of critical dimension measurement of a layer (col. 6, lines 48-55, col. 15, lines 21-33 and Fig. 18)

Nakayama does not expressly teach calculating the feedback process control signal of critical dimension measurement of a top layer in a previous manufacturing lot.

Saka teaches to calculating the feedback process control signal of critical dimension measurement of a top layer in a previous manufacturing lot (col. 12, lines 32-35).

Therefore, it would have been obvious to a person of ordinary skill in the art at the time of applicant's invention to modify the teaching of Nakayama to include calculating the feedback process control signal of critical dimension measurement of a top layer in a previous manufacturing lot to continuously and in-situ, monitor localized regions of a wafer surface during the critical dimension process (col. 5, lines 38-40).

18. As per claim 8, Nakayama teaches to calculating the compensation amount according to a polynomial function with a coefficient of the function being based on a measurement of a remaining thickness of a planarized interlayer (col. 6, lines 48-55) and calculating the feedback process control signal of critical dimension measurement of a layer (col. 15, lines 17-33).

Nakayama does not expressly teach a critical dimension measurement of a top layer in a previous manufacturing lot.

Saka teaches to a critical dimension measurement of a top layer in a previous manufacturing lot (col. 6, lines 58-60, col. 9, lines 28-33 and col. 12, lines 32-35).

Therefore, it would have been obvious to a person of ordinary skill in the art at the time of applicant's invention to modify the teaching of Nakayama to include a critical dimension measurement of a top layer in a previous manufacturing lot to continuously and in-situ, monitor localized regions of a wafer surface during the critical dimension process (col. 5, lines 38-40).

19. As per claim 12, Nakayama teaches a system for controlling exposure energy on a wafer substrate, comprising:

a feed forward controller (Fig. 18, element 45) providing a feed forward control signal to an exposure apparatus based on a thickness measurement of an interlayer of the wafer substrate for controlling the exposure energy focused on a top layer of the wafer substrate (col. 15, lines 14-41), and

a feed back controller (Fig. 18, element 45) providing a feed back exposure energy control signal to the exposure apparatus based on criteria dimension measurement of a layer of a wafer substrate (col. 15, lines 17-33).

Nakayama does not expressly teach a criteria dimension measurement of a top layer of a wafer substrate of a previous manufacturing lot.

Saka teaches to a critical dimension measurement of a top layer of a wafer substrate of a previous manufacturing lot (col. 6, lines 58-60, col. 9, lines 28-33 and col. 12, lines 32-35).

Therefore, it would have been obvious to a person of ordinary skill in the art at the time of applicant's invention to modify the teaching of Nakayama to include a critical dimension measurement of a top layer of wafer substrates of a previous manufacturing lot to continuously and in-situ, monitor localized regions of a wafer surface during the chemical mechanical planarization process (col. 5, lines 38-40).

20. As per claim 13, Nakayama teaches a thickness measurement device (Fig. 18, element 56) providing thickness measurement data to the feed forward controller (col. 15, lines 8-28 and Fig. 18, element 45).

21. As per claim 14, Nakayama teaches a criteria dimension measurement device (Fig. 18, element 56) providing criteria dimension measurement data to the feedback controller (Fig. 18, element 45 and col. 15, lines 8-28).

22. As per claim 15, Nakayama teaches a thickness measurement device (Fig. 18, element 56) providing thickness measurement data to the feed forward controller (Fig. 18, element 45 and col. 15, lines 8-28) and a criteria dimension measurement device

(Fig. 18, element 56) providing criteria dimension measurement data to the feedback controller (Fig. 18, element 45 and col. 15, lines 8-28).

23. As per claim 16, Nakayama teaches a thickness measurement device (Fig. 18, element 56) providing thickness measurement data of an shallow trench isolation layer of the wafer substrate to the feed forward controller (Fig. 18, element 45 and col. 15, lines 8-28).

24. As per claim 17, Nakayama teaches a criteria dimension measurement device (Fig. 18, element 56) providing criteria dimension measurement data of a poly-gate of wafer substrates (col. 15, lines 8-17).

Nakayama does not expressly teach to criteria dimension measurement data of a poly-gate of wafer substrates of a previous manufacturing lot.

Saka teaches to critical dimension measurement data of a poly-gate of wafer substrates of a previous manufacturing lot (col. 6, lines 58-60, col. 9, lines 28-33 and col. 12, lines 32-35).

Therefore, it would have been obvious to a person of ordinary skill in the art at the time of applicant's invention to modify the teaching of Nakayama to include critical

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dimension measurement data of a poly-gate of wafer substrates of a previous manufacturing lot to continuously and in-situ, monitor localized regions of a wafer surface during the chemical mechanical planarization process (col. 5, lines 38-40).

25. As per claim 18, Nakayama teaches to a thickness measurement device providing thickness measurement data of an shallow trench isolation layer of the wafer substrate to the feed forward controller (Fig. 18, element 45 and col. 15, lines 8-17); and a criteria dimension measurement device (Fig. 18, element 56) providing criteria dimension measurement data of a poly-gate (col. 15, lines 8-17).

Nakayama does not expressly teach to criteria dimension measurement data of a poly-gate of a previous manufacturing lot.

Saka teaches to critical dimension measurement data of a poly-gate of wafer substrates of a previous manufacturing lot (col. 6, lines 58-60, col. 9, lines 28-33 and col. 12, lines 32-35).

Therefore, it would have been obvious to a person of ordinary skill in the art at the time of applicant's invention to modify the teaching of Nakayama to include critical dimension measurement data of a poly-gate of wafer substrates of a previous

manufacturing lot to continuously and in-situ, monitor localized regions of a wafer surface during the chemical mechanical planarization process (col. 5, lines 38-40).

26. As per claim 19, Nakayama teaches the feed forward controller is user configurable by having one or more polynomial coefficients set to zero in a polynomial function model (col. 5, lines 12-33 and 38-51).

27. As per claim 20, Nakayama teaches the feed forward controller is user configurable by having one or more polynomial coefficients set to zero in a polynomial function model (col. 5, lines 12-33 and 38-51).

28. As per claim 21, Nakayama teaches a system as set forth above, comprising:
a thickness measurement device (Fig. 18, element 56) providing thickness measurement data of an shallow trench isolation layer of the wafer substrate to the feed forward controller (Fig. 18, element 45 and col. 15, lines 8-28).

29. As per claim 22, Nakayama teaches a criteria dimension measurement device (Fig. 18, element 56) providing criteria dimension measurement data of a poly-gate of wafer substrates (col. 15, lines 8-28).

Nakayama does not expressly teach to measurement data of a poly-gate of wafer a previous manufacturing lot.

Saka teaches to critical dimension measurement data (Fig .6) of a poly-gate of wafer substrates of a previous manufacturing lot (col. 6, lines 58-60, col. 9, lines 28-33 and col. 12, lines 32-35).

Therefore, it would have been obvious to a person of ordinary skill in the art at the time of applicant's invention to modify the teaching of Nakayama to include critical dimension measurement data of a poly-gate of wafer substrates of a previous manufacturing lot to continuously and in-situ, monitor localized regions of a wafer surface during the chemical mechanical planarization process (col. 5, lines 38-40).

Response to Arguments

30. Applicant's arguments, see pgs. 6-7, filed 30 May 2006 with respect to the rejection(s) of claim(s) 1-4 and 9-11 rejected under 35 U.S.C. 102(b) have been fully considered but they are not persuasive.

31. As per claim 1, with respect the applicant's argument the prior art fails to teach "a feed forward process control". The examiner respectfully disagrees.

Nakayama discloses, (col. 15, lines 12-21) "The data sent from the optical property measuring system 108 is used to correct the data sent from the optical property measuring system 56. Based on the results of correction, the process controlling system 45 calculates the optimum exposure energy as a process variable for the exposure step and also calculate variations in process conditions for the photoresist coating step." (col. 15, lines 27-41) "Then, exposure is carried out for the optimum exposure time, whereby stabilization of pattern size is contrived. The variations in process conditions for the photoresist coating step obtained by the process controlling system 45 are fed back through an interface 102 to the photoresist coating machine 49, in order to stabilize the photoresist coating and baking conditions.

In this embodiment, the optical property measuring system 108 and the optical property measuring system 56 can be connected to a plurality of photoresist coating machines to stabilize the photoresist coating and baking conditions constituting the production process conditions, and to a plurality of projection aligners fed with wafers for which the optimum exposure energy has been determined."

Hence, Nakayama discloses the feed forward process control, by using "the results of correction" (i.e. a compensation value determined based on the measured value outputted from the system) to calculate the optimum energy in process controlling system 45 to drive the system to a desired response.

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32. Claims 2-4 and 9-11 stand rejected under 35 U.S.C 102(b) over Nakayama as set forth above.

33. Applicant's arguments, see pg. 7, filed 30 May 2006 with respect to the rejection(s) of claim(s) 5-8 and 12-22 rejected under 35 U.S.C. 103(a) have been fully considered but they are not persuasive.

34. As per claim 12, with respect the applicant's argument the prior art fails to teach "a feed forward process." The examiner respectfully disagrees.

Nakayama discloses, (col. 15, lines 12-21) "The data sent from the optical property measuring system 108 is used to correct the data sent from the optical property measuring system 56. Based on the results of correction, the process controlling system 45 calculates the optimum exposure energy as a process variable for the exposure step and also calculate variations in process conditions for the photoresist coating step." (col. 15, lines 27-41) "Then, exposure is carried out for the optimum exposure time, whereby stabilization of pattern size is contrived. The variations in process conditions for the photoresist coating step obtained by the process controlling system 45 are fed back through an interface 102 to the photoresist coating machine 49, in order to stabilize the photoresist coating and baking conditions.

In this embodiment, the optical property measuring system 108 and the

optical property measuring system 56 can be connected to a plurality of photoresist coating machines to stabilize the photoresist coating and baking conditions constituting the production process conditions, and to a plurality of projection aligners fed with wafers for which the optimum exposure energy has been determined.”

Hence, Nakayama discloses the feed forward process control, by using “the results of correction” (i.e. a compensation value determined based on the measured value outputted from the system) to calculate the optimum energy in process controlling system 45 to drive the system to a desired response.

35. Claims 5-8 and 13-22 stand rejected under 35 U.S.C 103(a) over Nakayama over Saka as set forth above.

Conclusion

THIS ACTION IS MADE FINAL. Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of

the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the mailing date of this final action.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Jennifer L. Norton whose telephone number is 571-272-3694. The examiner can normally be reached on 8:00 a.m. - 4:30 p.m..

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Anthony Knight can be reached on 571-272-3687. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see <http://pair-direct.uspto.gov>. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.



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Art Unit 2121